New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.
SPRINGFIELD, NEW JERSEY 07081
U.S.A.

TELEPHONE: (973) 376-29
(212) 227-60
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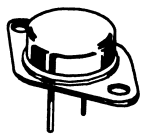
Complementary Silicon High-Power Transistors

. . . PowerBase™ complementary transistors designed for high power audio, stepping motor and other linear applications. These devices can also be used in power switching circuits such as relay or solenoid drivers, dc–to–dc converters, inverters, or for inductive loads requiring higher safe operating area than the 2N3055 and MJ2955.

- Current–Gain — Bandwidth–Product @ I_C = 1.0 Adc
  f_T = 0.8 MHz (Min) – NPN
  = 2.2 MHz (Min) – PNP
- Safe Operating Area — Rated to 60 V and 120 V, Respectively

NPN
2N3055A
MJ15015
MJ2955A
PNP
MJ15016

15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60, 120 VOLTS 115, 180 WATTS



CASE 1–07 TO–204AA (TO–3)

***MAXIMUM RATINGS**

Rating	Symbol	2N3055A MJ2955A	MJ15015 MJ15016	Unit
Collector–Emitter Voltage	V_{CEO}	60	120	Vdc
Collector–Base Voltage	V_{CBO}	100	200	Vdc
Collector–Emitter Voltage Base Reversed Biased	V_{CEV}	100	200	Vdc
Emitter–Base Voltage	V_{EBO}	7.0		Vdc
Collector Current — Continuous	I_C	15		Adc
Base Current	I_B	7.0		Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	115 0.65	180 1.03	Watts W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +200		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.52	0.98	°C/W

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2N3055A MJ15015 MJ2955A MJ15016

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS (1)					
*Collector–Emitter Sustaining Voltage (I_C = 200 mAdc, I_B = 0)	2N3055A, MJ2955A MJ15015, MJ15016	$V_{CEO(sus)}$	60 120	— —	Vdc
Collector Cutoff Current		I_{CEO}			mAdc
(V_{CE} = 30 Vdc, $V_{BE(off)}$ = 0 Vdc)	2N3055A, MJ2955A		—	0.7	
(V_{CE} = 60 Vdc, $V_{BE(off)}$ = 0 Vdc)	MJ15015, MJ15016		—	0.1	
*Collector Cutoff Current (V_{CEV} = Rated Value, $V_{BE(off)}$ = 1.5 Vdc)	2N3055A, MJ2955A MJ15015, MJ15016	I_{CEV}	— —	5.0 1.0	mAdc
Collector Cutoff Current		I_{CEV}			mAdc
(V_{CEV} = Rated Value, $V_{BE(off)}$ = 1.5 Vdc, T_C = 150°C)	2N3055A, MJ2955A MJ15015, MJ15016		— —	30 6.0	
Emitter Cutoff Current (V_{EB} = 7.0 Vdc, I_C = 0)	2N3055A, MJ2955A MJ15015, MJ15016	I_{EBO}	— —	5.0 0.2	mAdc
***SECOND BREAKDOWN**					
Second Breakdown Collector Current with Base Forward Biased		$I_{S/b}$			Adc
(t = 0.5 s non–repetitive)	2N3055A, MJ2955A		1.95	—	
(V_{CE} = 60 Vdc)	MJ15015, MJ15016		3.0	—	
***ON CHARACTERISTICS (1)**					
DC Current Gain		h_{FE}			—
(I_C = 4.0 Adc, V_{CE} = 2.0 Vdc)			10	70	
(I_C = 4.0 Adc, V_{CE} = 4.0 Vdc)			20	70	
(I_C = 10 Adc, V_{CE} = 4.0 Vdc)			5.0	—	
Collector–Emitter Saturation Voltage		$V_{CE(sat)}$			Vdc
(I_C = 4.0 Adc, I_B = 400 mAdc)			—	1.1	
(I_C = 10 Adc, I_B = 3.3 Adc)			—	3.0	
(I_C = 15 Adc, I_B = 7.0 Adc)			—	5.0	
Base–Emitter On Voltage (I_C = 4.0 Adc, V_{CE} = 4.0 Vdc)		$V_{BE(on)}$	0.7	1.8	Vdc
***DYNAMIC CHARACTERISTICS**					
Current–Gain — Bandwidth Product (I_C = 1.0 Adc, V_{CE} = 4.0 Vdc, f = 1.0 MHz)	2N3055A, MJ15015 MJ2955A, MJ15016	f_T	0.8 2.2	6.0 18	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C_{ob}	60	600	pF
***SWITCHING CHARACTERISTICS (2N3055A only)**					
RESISTIVE LOAD					
Delay Time	(V_{CC} = 30 Vdc, I_C = 4.0 Adc, I_{B1} = I_{B2} = 0.4 Adc, t_p = 25 µs Duty Cycle ≤ 2%)	t_d	—	0.5	µs
Rise Time		t_r	—	4.0	µs
Storage Time		t_s	—	3.0	µs
Fall Time		t_f	—	6.0	µs

(1) Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤ 2%.

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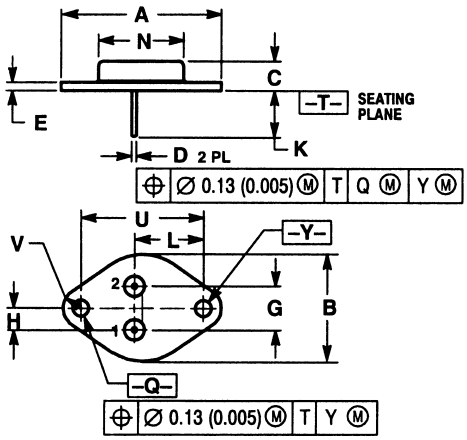
2N3055A MJ15015 MJ2955A MJ15016

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR